Unit: mm

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TOSHIBA Transistor Silicon NPN Triple Diffused Type

## 2SC6034

High-Speed, High-Voltage Switching Applications Switching Regulator Applications DC-DC Converter Applications

• High-speed switching:  $t_f = 0.24 \mu s \text{ (max) (IC} = 0.3 \text{ A)}$ 

#### **Absolute Maximum Ratings (Ta = 25°C)**

Characteristic		Symbol	Rating	Unit	
Collector-base voltage		$V_{CBO}$	600	V	
Collector-emitter voltage		V <sub>CEO</sub>	285	V	
Emitter-base voltage		V <sub>EBO</sub>	8	V	
Collector current	DC	IC	1.0	Α	
	Pulse	I <sub>CP</sub>	2.0		
Base current		ΙΒ	0.5	Α	
Collector power dissipation	Ta = 25°C	PC	1.0	W	
Junction temperature		Tj	150	°C	
Storage temperature range		T <sub>stg</sub>	-55 to 150	°C	

7.1MAX
3.8
3.2
0.55 - 0.05
0.85
0.45 - 0.05
1 2 3 1.025 ± 0.05
1 2 3 1.025 ± 0.05

1 Base
2 Collector
3 Emitter

TOSHIBA 2-7D101A

Weight: 0.2 g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in

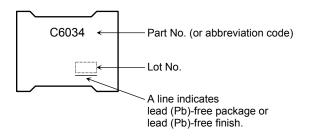
temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).



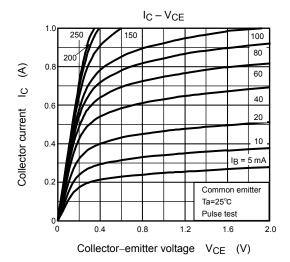
# www.DataSheet4U.com **Characteristics (Ta = 25°C)**

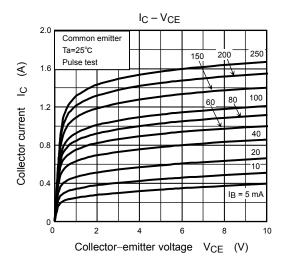
Chara	Characteristic Symbol Test Condition		Min	Тур.	Max	Unit	
Collector cut-off current		I <sub>CBO</sub>	V <sub>CB</sub> = 600 V, I <sub>E</sub> = 0	_	_	100	μΑ
Emitter cut-off current		I <sub>EBO</sub>	V <sub>EB</sub> = 8 V, I <sub>C</sub> = 0	_	_	100	μΑ
Collector-base breakdown voltage		V (BR) CBO	I <sub>C</sub> = 1 mA, I <sub>B</sub> = 0	600	_	_	V
Collector-emitter b	oreakdown voltage	V (BR) CEO	$I_{\rm CEO}$ $I_{\rm C} = 10 \text{ mA}, I_{\rm B} = 0$		_	_	V
DC current gain		h <sub>FE (1)</sub>	V <sub>CE</sub> = 5 V, I <sub>C</sub> = 1 mA	100	_	250	
		h <sub>FE (2)</sub>	V <sub>CE</sub> = 5 V, I <sub>C</sub> = 0.1 A	125	_	250	
		h <sub>FE (3)</sub>	V <sub>CE</sub> = 5 V, I <sub>C</sub> = 0.2 A	80	_	_	
Collector emitter saturation voltage		V <sub>CE</sub> (sat)	I <sub>C</sub> = 0.6 A, I <sub>B</sub> = 75 mA	-	_	1.0	V
Base-emitter saturation voltage		V <sub>BE (sat)</sub>	I <sub>C</sub> = 0.6 A, I <sub>B</sub> = 75 mA	_	_	1.3	V
Switching time Sto	Rise time	t <sub>r</sub>	20 μs V <sub>CC</sub> ≈ 200 V  B1  B2  B1  OUT- PUT  INPUT	_	_	0.4	
	Storage time	t <sub>stg</sub>		_	_	3.5	μs
	Fall time	t <sub>f</sub>	$I_{B1}$ = 20 mA, $-I_{B2}$ = 50 mA DUTY CYCLE ≤ 1%	_	_	0.24	

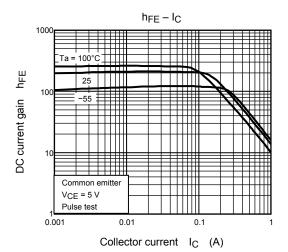
### Marking

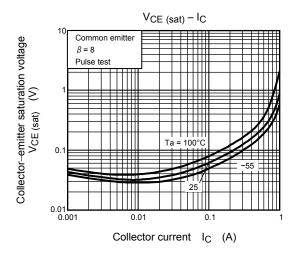


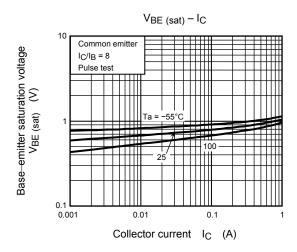
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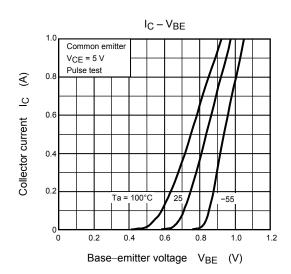




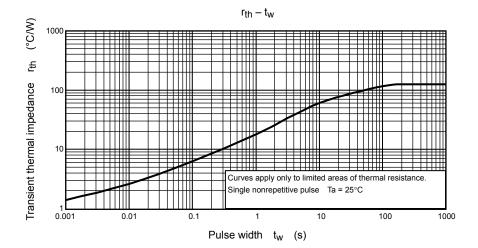


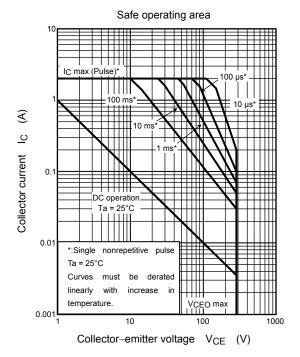


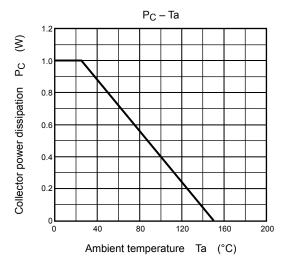




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